



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Volker Haerle  
Serial No. : 10/625,118  
Filed : July 22, 2003  
Title : METHOD OF PRODUCTION OF SEMICONDUCTOR COMPONENTS

Art Unit : Unknown  
Examiner : Unknown

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Copies of the references listed on the attached form PTO-1449 are enclosed.

This statement is being filed within three months of the filing date of the application or before the receipt of a first Office action on the merits. Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: 8/14/03

David J. Goren  
David J. Goren  
Reg. No. 34,609

Fish & Richardson P.C.  
500 Arguello Street, Suite 500  
Redwood City, California 94063  
Telephone: (650) 839-5070  
Facsimile: (650) 839-5071

50169140.doc

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Date of Deposit August 14, 2003

Signature [Signature]

Nikia M. Mc Nillion  
Typed or Printed Name of Person Signing Certificate

Substitute Form PTO-1449

U.S. Department of Commerce  
Patent and Trademark OfficeAttorney's Docket No.  
12406-059US2Application No.  
10/625,118**Information Disclosure Statement  
by Applicant**

Use several sheets if necessary)

AUG 25 2003

(37 CFR §1.98)

Applicant  
Volker HaerleFiling Date  
July 22, 2003Group Art Unit  
Unknown**U.S. Patent Documents**

Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

**Foreign Patent Documents or Published Foreign Patent Applications**

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AL							
	AM							
	AN							
	AO							
	AP							

**Other Documents (include Author, Title, Date, and Place of Publication)**

Examiner Initial	Desig. ID	Document
	AQ	B. Henle, et, al., "In Situ Selective Area Etching and Mowpe Regrowth Of GainsAs-InP ON InP Substrates," Int. Conf. On Indium Phosphide & Rel. Materials, U.S. NY, IEEE, Bd. CONF 4, S. pgs. 159-162
	AR	
	AS	
	AT	

Examiner Signature

Date Considered

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.